

PHOTOVOLTAIC DIODE

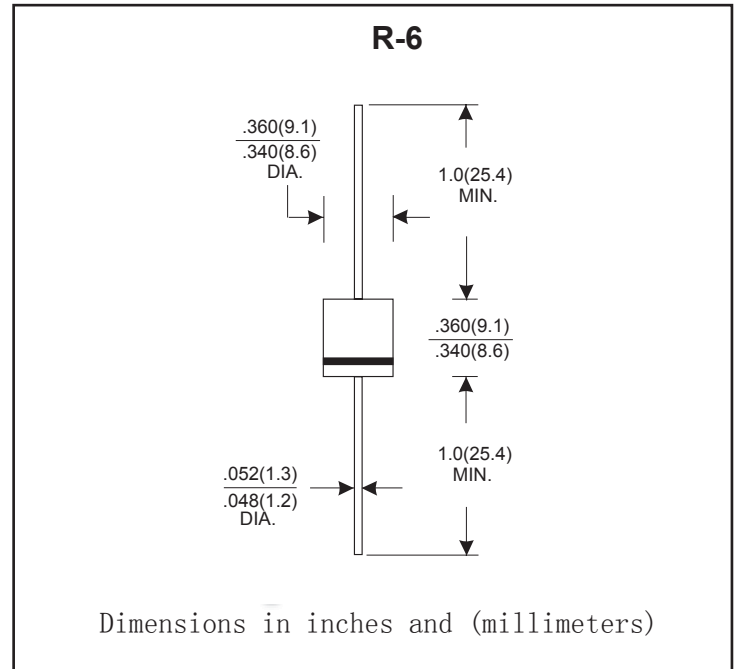
VOLTAGE RANGE: 30--- 100 V CURRENT: 15.0 A

FEATURES

- Metal of silicon rectifier
- majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

MECHANICAL DATA

- Case: R-6 molded plastic body
- Lead:Plated axial leads,solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end
- Mounting Position:Any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate by 20%.

CHARACTERISTICS	SYMBOL	15SQ030	15SQ035	15SQ040	15SQ045	15SQ050	15SQ060	15SQ080	15SQ100	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	30	35	40	45	50	60	80	100	V
Maximum RMS Voltage	V _{RMS}	21	24.5	28	31.5	35	42	56	70	V
Maximum DC Blocking Voltage	V _{DC}	30	35	40	45	50	60	80	100	V
Maximum Average Forward Rectified Current @T _c =95 °C	I _(AV)	15								A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load(JEDEC Method)	I _{FSM}	275								A
Peak Forward Voltage at 15A DC(Note1)	V _F	0.55			0.7		0.8			V
Maximum DC Reverse Current @T _j =25°C at Rated DC Blocking Voltage @T _j =125°C	I _R	0.1				50				mA
Typical Junction Capacitance (Note2)	C _J	450								pF
Typical Thermal Resistance (Note2)	R _{θJc}	3								°C/W
Junction temperature Range in DC forward mode	T _J	-55 to+175				200				°C
Storage Temperature Range	T _S	-55 to+175								°C
ESD	VESD	15000								V

NOTES:1.300us Pulse Width, 2%Duty Cycle.
2.Measured at 1.0 MHZ and applied reverse voltage of 4.0VDC.
3.Thermal Resistance Junction to case.

RATINGS AND CHARACTERISTIC CURVES

FIG.1-FORWARD CURRENT DERATING CURVE

FIG.2-MAXIMUM NON-REPETITIVE SURGE

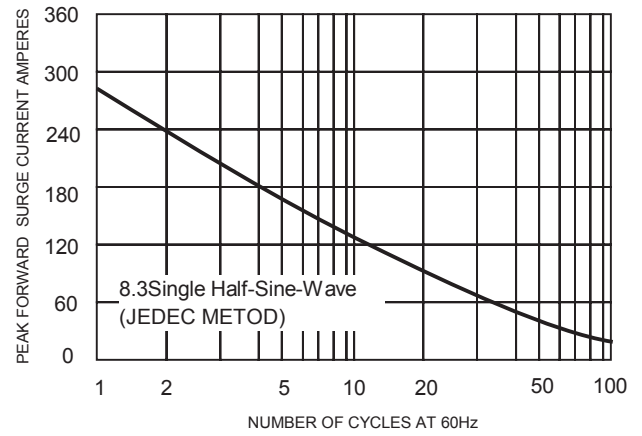
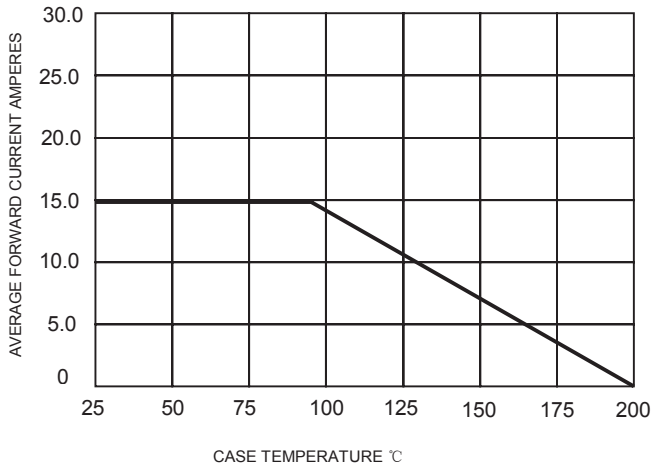


FIG.3-TYPICAL REVERSE CHARACTERISTICS

FIG.4-TYPICAL FORWARD CHARACTERISTICS

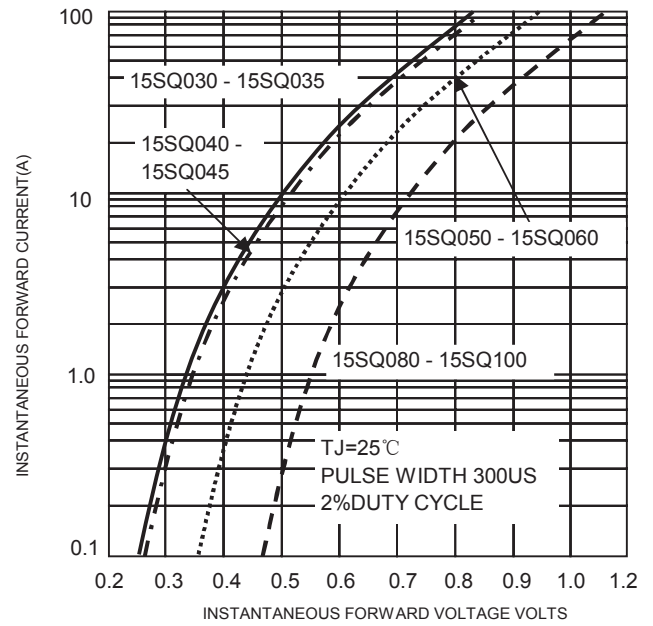
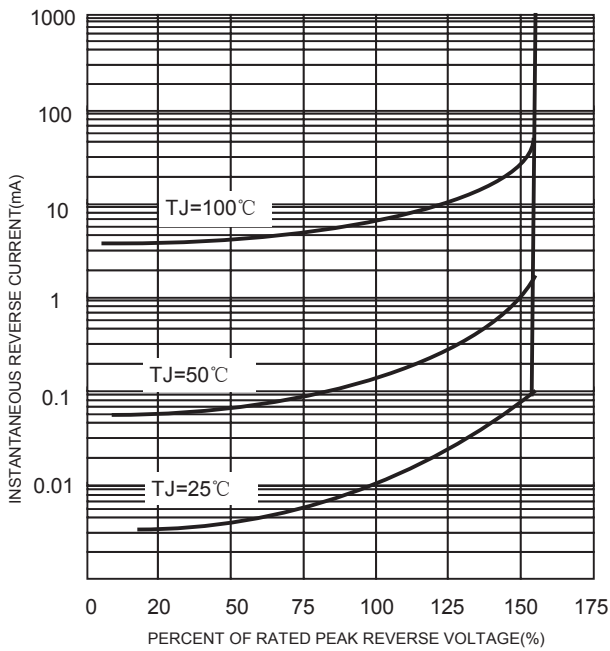


FIG.5-TYPICAL JUNCTION CAPACITANCE

